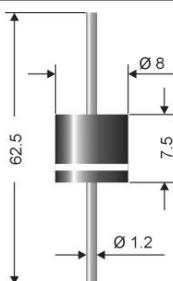


SBH 1820 ... SBH 1845



Axial lead diode

High temperature schottky barrier diodes

SBH1820 ... SBH1845

Forward Current: 18 A

Reverse Voltage: 20 to 45 V

Preliminary Data

Features

- Max. solder temperature: 260°C
- Plastic material has UL classification 94V-0

Mechanical Data

- Plastic case: 8 x 7,5 [mm]
- Weight approx.: 1,5 g
- Terminals: plated terminals solderable per MIL-STD-750
- Mounting position: any
- Standard packaging: 500 pieces per ammo or 1 000 pieces per reel

1) Valid, if leads are kept at ambient temperature at a distance of 10 mm from case

2) $I_F = 5 \text{ A}$, $V_F @ 18\text{A} < 0,56 \text{ V}$, $T_j = 25 \text{ }^\circ\text{C}$

3) $T_A = 25 \text{ }^\circ\text{C}$

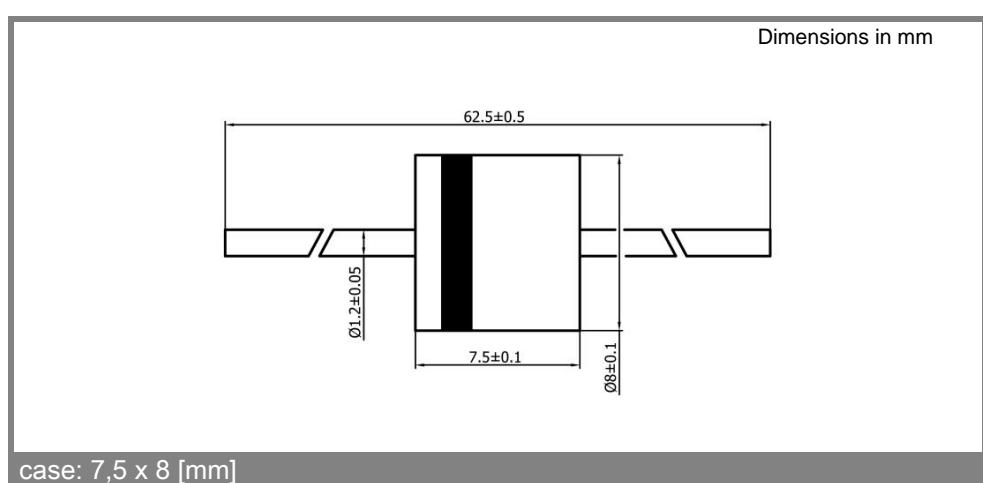
4) Thermal resistance from junction to lead/terminal at a distance 0 mm from case

5) Max. junction temperature $T_j \leq 200 \text{ }^\circ\text{C}$ in reverse mode $V_R = 50\% V_{RRM}$ and in bypass mode / DC forward mode

Type	Repetitive peak reverse voltage V_{RRM} V	Surge peak reverse voltage V_{RSM} V	Max. reverse recovery time $I_F = - A$ $I_R = - A$ $I_{RR} = - A$ t_{rr} ns	Max. forward voltage $V_F^{2)}$
SBH 1820	20	20	-	0,46
SBH 1830	30	30	-	0,46
SBH 1840	40	40	-	0,46
SBH 1845	45	45	-	0,46

Absolute Maximum Ratings		$T_A = 25 \text{ }^\circ\text{C}$, unless otherwise specified	
Symbol	Conditions	Values	Units
I_{FAV}	Max. averaged fwd. current, R-load, $T_A = 50 \text{ }^\circ\text{C}$ ¹⁾	18	A
I_{FRM}	Repetitive peak forward current $f > 15 \text{ Hz}$ ¹⁾	70	A
I_{FSM}	Peak forward surge current 10 Hz half sinus-wave ³⁾	600	A
i^2t	Rating for fusing, $t < 10 \text{ ms}$ ³⁾	1800	A ² s
R_{thA}	Max. thermal resistance junction to ambient ¹⁾		K/W
R_{thL}	Max. thermal resistance junction to terminals ⁴⁾	2,5	K/W
T_j	Operating junction temperature	- 50 ... + 185 ($T_j \leq 200 \text{ }^\circ\text{C}$ in reverse mode $V_R = 50\% V_{RRM}$ ⁵⁾)	$^\circ\text{C}$
T_s	Storage temperature	- 50 ... + 175	$^\circ\text{C}$

Characteristics		$T_A = 25 \text{ }^\circ\text{C}$, unless otherwise specified	
Symbol	Conditions	Values	Units
I_R	Maximum leakage current, $T_j = 25 \text{ }^\circ\text{C}$; $V_R = V_{RRM}$	< 75	μA
	$T_j = \text{ }^\circ\text{C}$; $V_R = V_{RRM}$		
C_J	Typical junction capacitance (at MHz and applied reverse voltage of V)	-	pF
Q_{rr}	Reverse recovery charge ($U_R = V$; $I_F = A$; $dI_F/dt = A/\text{ms}$)	-	μC
E_{RSM}	Non repetitive peak reverse avalanche energy ($I_R = \text{mA}$; $T_j = \text{ }^\circ\text{C}$; inductive load switched off)	-	mJ



SBH 1820 ... SBH 1845

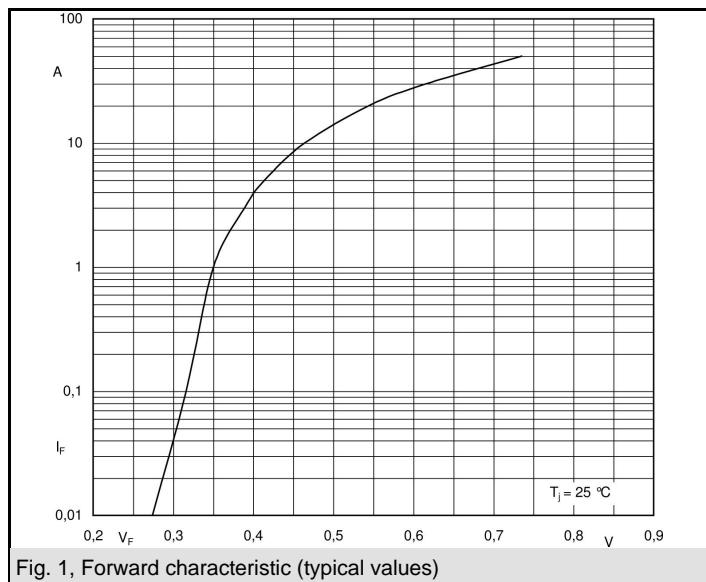


Fig. 1, Forward characteristic (typical values)

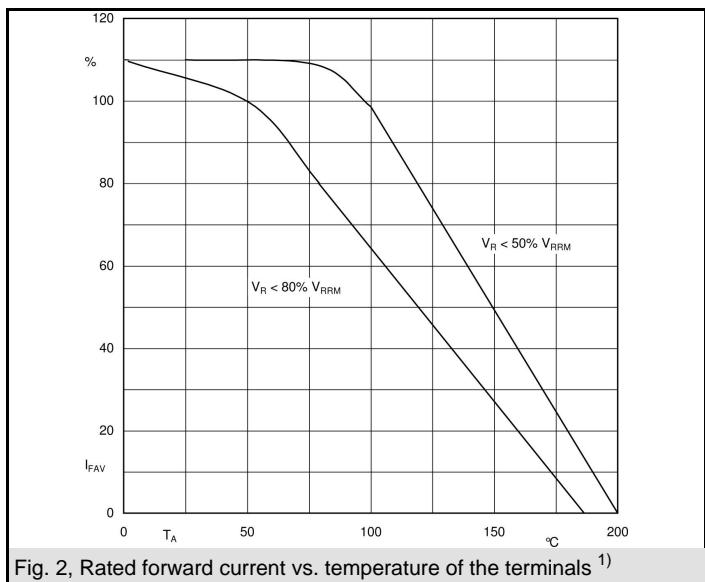


Fig. 2, Rated forward current vs. temperature of the terminals¹⁾

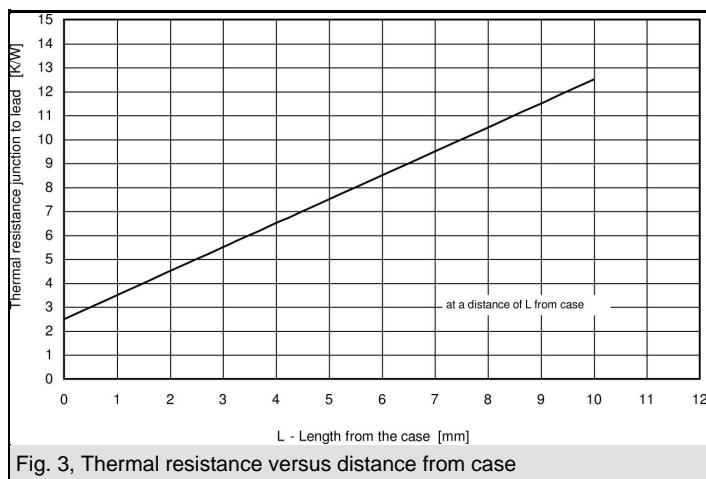


Fig. 3, Thermal resistance versus distance from case